

View Online at <https://aerobasegroup.com/nsn/5962-01-370-1470>

Maximum Power Dissipation Rating:

1.04 watts

Operating Temperature Range:

-55.0/+125.0 degrees celsius

Storage Temperature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Bipolar

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Bipolar metal-oxide semiconductor

Case Outline Source And Designator:

D-3 mil-m-38510

Current Rating Per Characteristic:

100.00 milliamperes reverse current, dc

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, digital, schottky, bipolar 65536 bit prom

Voltage Rating And Type Per Characteristic:

-0.3 volts total supply and 7.0 volts total supply

Time Rating Per Characteristic:

55.00 nanoseconds af output megawatts

Memory Device Type:

Prom

Hybrid Technology Type:

Monolithic

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fig:

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